Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-275-7332

Inclosure Material:

Metal

Overall Length:

1.276 inches

Overall Height:

0.340 inches

Overall Width:

0.700 inches

Mounting Facility Quantity:

2

Internal Configuration:

Junction contact

Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-66

Electrode Internally-electrically Connected To Case:

Anode

Mounting Method:

Unthreaded hole

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

200.0 repetitive peak off-state voltage

Current Rating Per Characteristic:

3.20 amperes forward current, total rms nanoamperes

Maximum Operating Tempurature Per Measurement Point:

50.0 degrees celsius case

Special Features:

Junction pattern arrangement: pnpnp

Terminal Type And Quantity:

2 unthreaded hole and 1 case

Shelf Life:

N/a

Unit Of Measure:

--

Demilitarization:

No

Fiig:

A110a0